

Supplementary Information

Skutterudite with Graphene-modified Grain-boundary Complexion Enhances zT Enabling High-efficiency Thermoelectric Device

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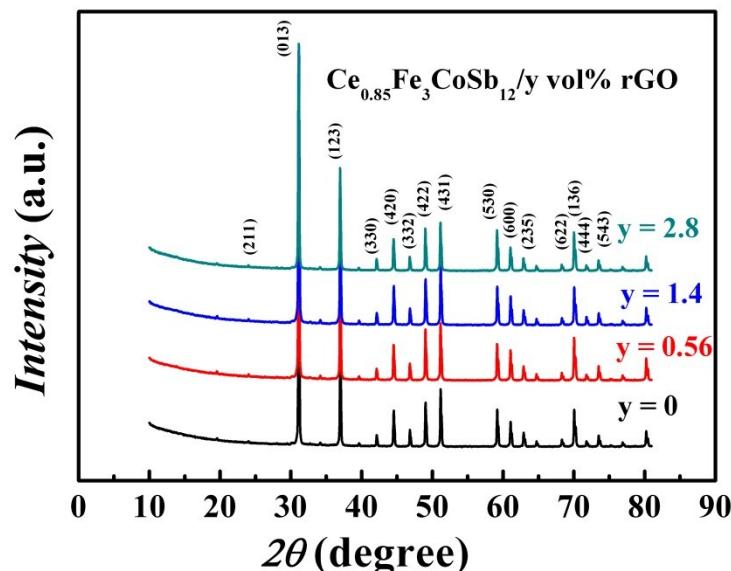


Fig. S1 Powder X-ray diffraction patterns of the Ce_{0.85}Fe₃CoSb₁₂/y vol% rGO (y = 0, 0.56, 1.4, 2.8)

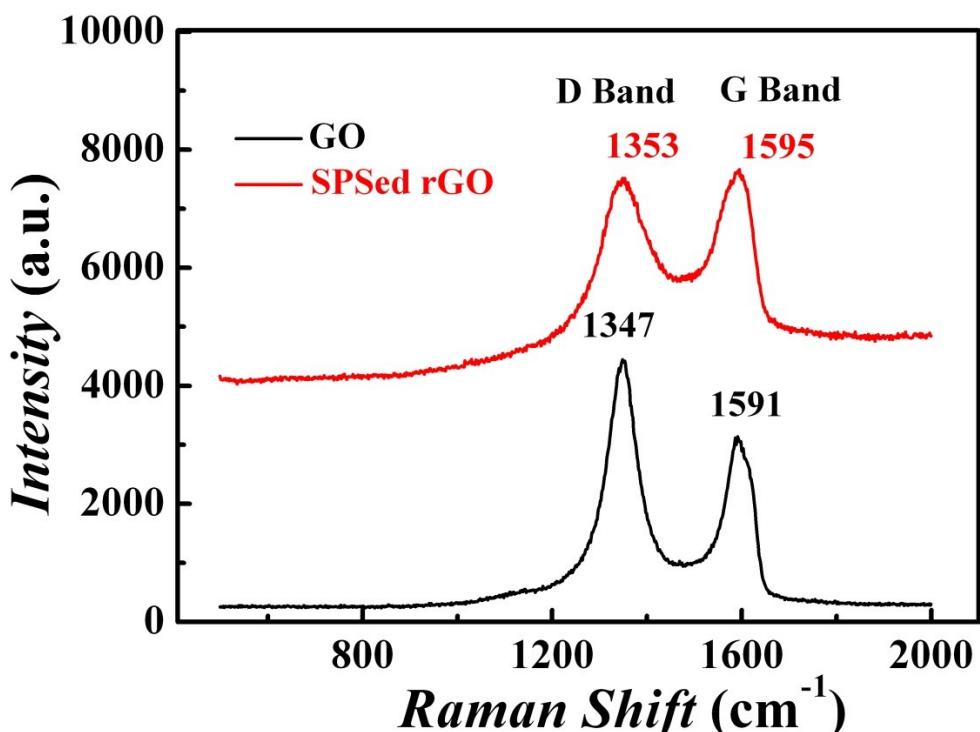


Fig. S2 Raman Spectra of GO and 850K-SPSed rGO

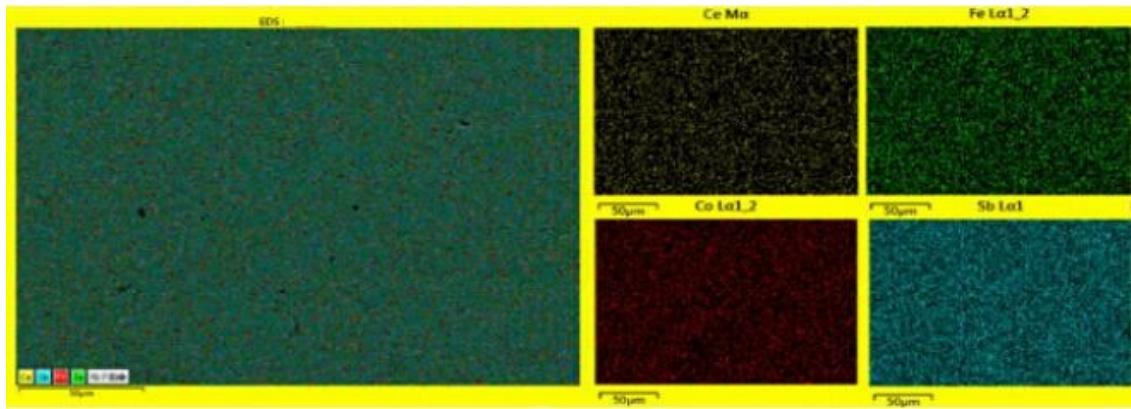


Fig. S3 The EDS image of bulk $\text{Ce}_{0.85}\text{Fe}_3\text{CoSb}_{12}/y$ vol% rGO ($y = 2.8$).

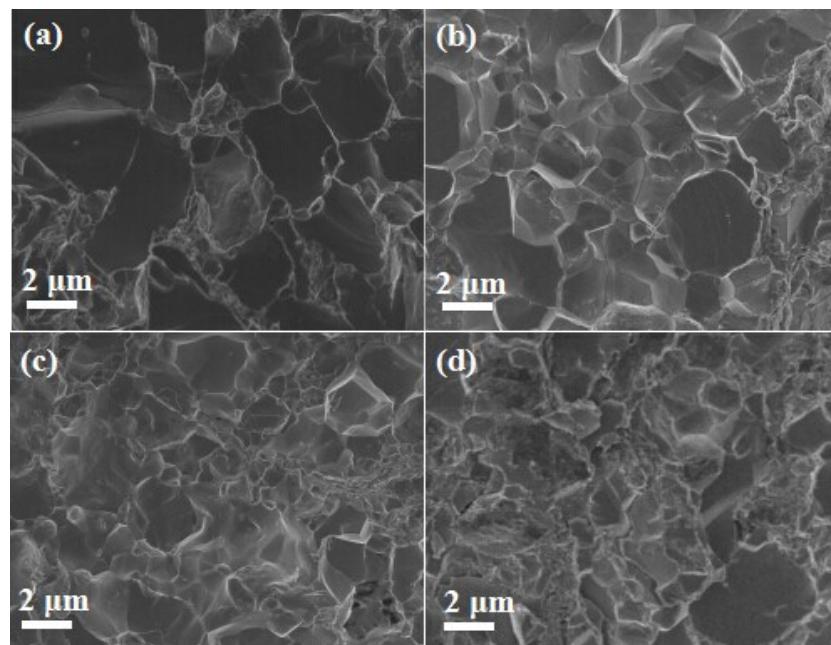


Fig. S4 (a-d) The surface SEM image of bulk $\text{Ce}_{0.85}\text{Fe}_3\text{CoSb}_{12}/y$ vol% rGO ($y = 0, 0.56, 1.4, 2.8$)

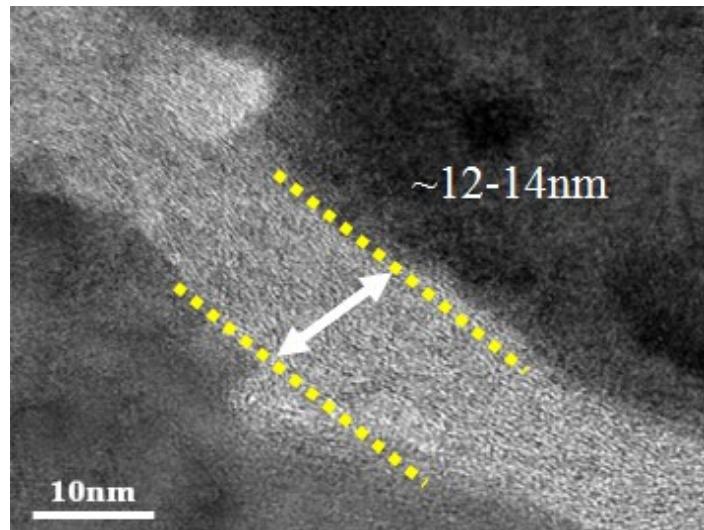


Fig. S5 The cross section HRTEM image of bulk $\text{Ce}_{0.85}\text{Fe}_3\text{CoSb}_{12}/2.8$ vol% rGO

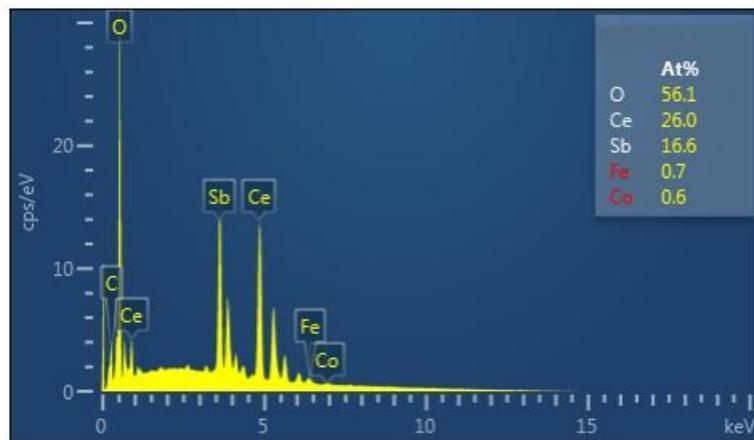


Fig. S6 EDS of the nano precipitate in Fig. 2d

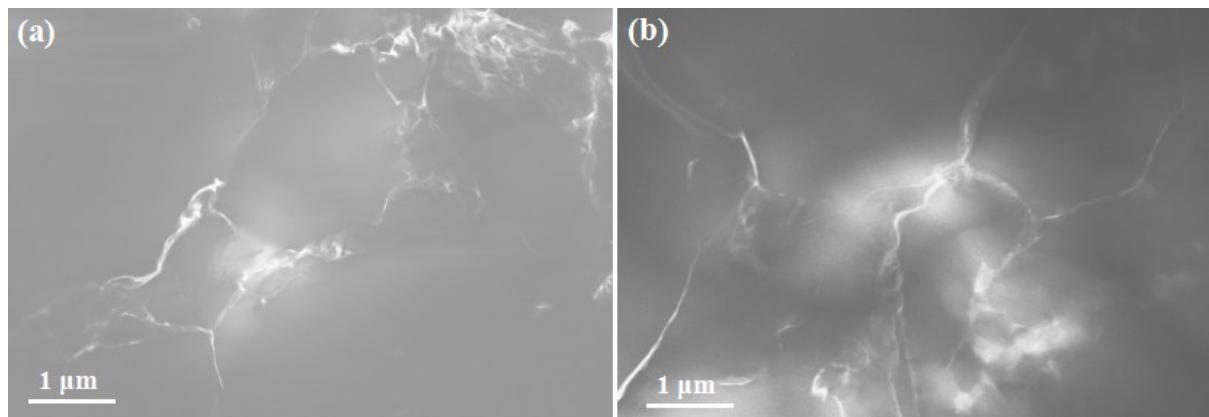


Fig. S7 HAADF-STEM image of the p-type $\text{Ce}_{0.85}\text{Fe}_3\text{CoSb}_{12}/0.56$ vol% rGO wrapping sample

Table S1. Comparison of the carrier concentration (p), mobility (μ), electrical conductivity (σ), hall coefficient (R_h), Seebeck coefficient (S) and power factor (PF) of $\text{Ce}_{0.85}\text{Fe}_3\text{CoSb}_{12}/y$ vol % rGO ($y = 0, 0.56, 1.4, 2.8$) at 300 K.

Samples (vol% rGO)	p (10^{20} cm $^{-3}$)	μ (cm 2 V $^{-1}$ s $^{-1}$)	σ (10 5 Sm $^{-1}$)	R_h (10 $^{-2}$ cm 3 C $^{-1}$)	S (μ VK $^{-1}$)	PF (μ Wcm $^{-1}$ K $^{-2}$)
0	19.6	3.6	1.11	0.32	109.9	13.5
0.56	20.7	3.3	1.10	0.30	112.4	14.0
1.40	22.1	3.1	1.09	0.28	116.8	15.0
2.80	27.3	2.3	1.00	0.22	112.5	12.7